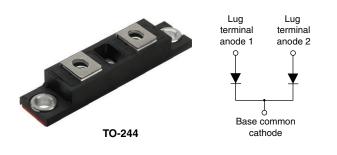
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 200 A



200 A

45 V

TO-244

Two diodes common cathode

**PRIMARY CHARACTERISTICS** 

I<sub>F(AV)</sub>

 $V_{R}$ 

Package

Circuit configuration

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		_
EEV	TURE	C.
	IONE	9

- 150 °C T<sub>J</sub> operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

The VS-200CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UN						
I <sub>F(AV)</sub>	Rectangular waveform	200	А					
V <sub>RRM</sub>		45	V					
I <sub>FSM</sub>	$t_p = 5 \ \mu s \ sine$	26 000	А					
V <sub>F</sub>	100 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.52	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-200CNQ045PbF	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	45	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average	per leg		100	100	•			
forward current See fig. 5	per device	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 116 °C	200	A			
Maximum peak one cycle non-repetitive surge current per leg			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	26 000	^		
See fig. 7	rent per leg	IFSM	IFSM	10 ms sine or 6 ms rect. pulse rated V <sub>RRM</sub> applied			1550	A
Non-repetitive avalanch	e energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 17 A, L = 1 mH		135	mJ		
Repetitive avalanche cu	rrent per leg	$I_{AR} \qquad \begin{array}{c} \mbox{Current decaying linearly to zero in 1 } \mu \mbox{s} \\ \mbox{Frequency limited by } T_J \mbox{ maximum } V_A = 1.5 \mbox{ x } V_R \mbox{ typical} \end{array}$		20	А			

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL				

PARAMETER	SYMBOL	TEST CO	VALUES	UNITS	
		100 A	T <sub>.1</sub> = 25 °C	0.55	V
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	200 A	IJ=25 C	0.73	
See fig. 1	VFM (')	100 A	T 105 %C	0.52	v
		200 A	T <sub>J</sub> = 125 °C	0.69	
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	10	mA
See fig. 2	IRM (17	T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	800	
Threshold voltage	V <sub>F(TO)</sub>	T <sub>J</sub> = T <sub>J</sub> maximum		0.27	V
Forward slope resistance	r <sub>t</sub>			2.0	mΩ
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal ran	5200	pF	
Typical series inductance per leg	L <sub>S</sub>	From top of terminal hole	7.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs	

#### Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temper	ature range	T <sub>J</sub> , T <sub>Stg</sub>	- 55	-	150	°C
per leg		Р	-	-	0.38	
Thermal resistance, junction to case	per module	R <sub>thJC</sub>	-	-	0.19	°C/W
Thermal resistance, case to heatsink		R <sub>thCS</sub>	-	0.10	-	
M/-i-h+			_	68	_	g
Weight			-	2.4	-	oz.
Mounting torque			35.4 (4)	-	53.1 (6)	
Mounting torque center hole			30 (3.4)	-	40 (4.6)	lbf · in (N · m)
Terminal torque			30 (3.4)	-	44.2 (5)	(,
Vertical pull			-	-	80	lbf ⋅ in
2" lever pull			-	-	35	חויוטו

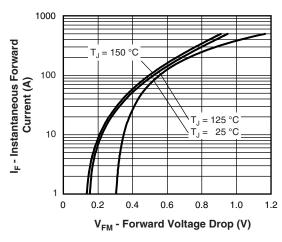
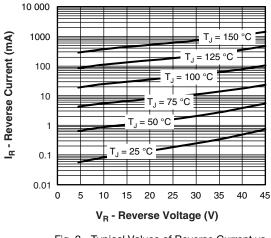
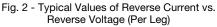


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





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# VS-200CNQ045PbF

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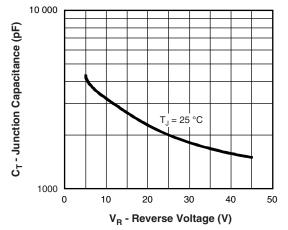


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

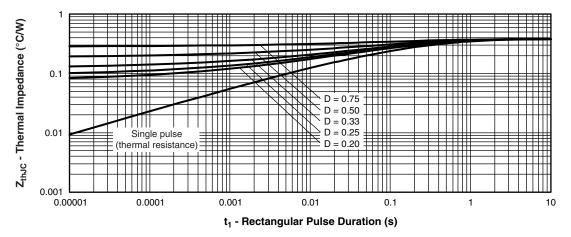
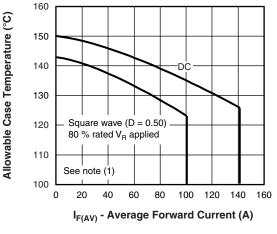
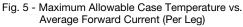


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)





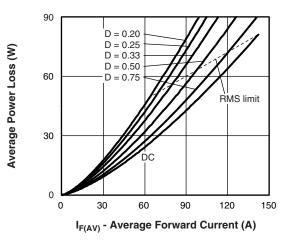


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

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# VS-200CNQ045PbF

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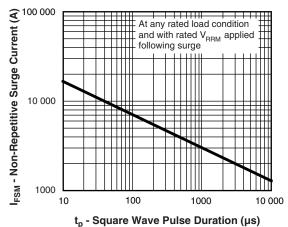


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

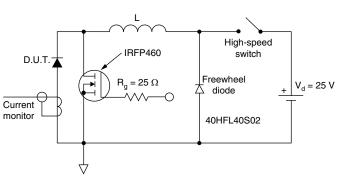


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R at V_{R1} = 80 \%$  rated  $V_R$ 

## **ORDERING INFORMATION TABLE**

Device code	VS-	20	0	С	Ν	Q	045	PbF
		2	3	4	5	6	7	8
	1 - 2 -	Ave	erage cu	niconduo Irrent rat	ing (x 1	0)		
	3 - 4 -			con ider configura		n		
	5 -	N =	not isol	ated				
	6 -	Q =	Schottl	<y rectifi<="" th=""><th>er diode</th><th>•</th><th></th><th></th></y>	er diode	•		
	7 -	Vol	tage rati	ing (045	= 45 V)	1		
	8 -	Lea	nd (Pb)-f	ree				

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95021						
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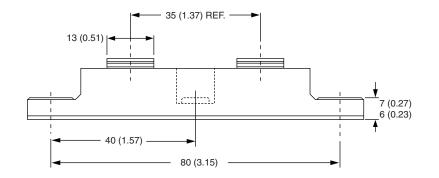


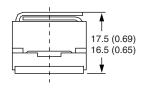


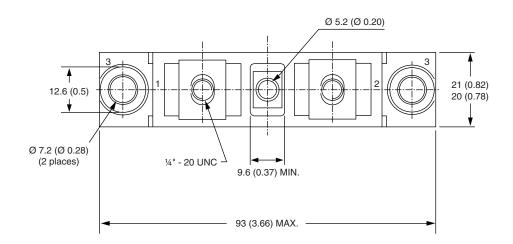
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**TO-244** 

### **DIMENSIONS** in millimeters (inches)









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